3Q Hi-Com Triac Rev. 02 — 29 November 2010

Product data sheet

1. Product profile

1.1 General description

Planar passivated high commutation three quadrant triac in a SOT78 plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series C" triac will commutate the full RMS current at the maximum rated junction temperature without the aid of a snubber.

1.2 Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt

1.3 Applications

- Electronic thermostats (heating and cooling)
- High power motor controls e.g. washing machines and vacuum cleaners

1.4 Quick reference data

- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

| Table 1. | Quick reference da | ata | | | | |
|---------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off-state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ see } Figure 4;$ see Figure 5 | - | - | 95 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 101 °C; see <u>Figure 3</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u> | - | - | 12 | A |



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| Table 1. | Quick reference | datacontinued | | | | |
|----------------|-------------------------|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static cha | aracteristics | | | | | |
| | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; see <u>Figure 7</u> | 2 | - | 35 | mA |
| | | $V_D = 12 V; I_T = 0.1 A; T2+ G-;$ $T_j = 25 °C; see Figure 7$ | 2 | - | 35 | mA |
| | | $V_D = 12 V; I_T = 0.1 A; T2-G-;$ $T_j = 25 °C; see Figure 7$ | 2 | - | 35 | mA |

Table 1 Outlate rafe .

Pinning information 2.

| Table 2 | . Pinniı | ng information | | |
|---------|----------|--------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | | N. |
| 2 | T2 | main terminal 2 | mb | |
| 3 | G | gate | | Sym051 |
| mb | Τ2 | mounting base; main terminal 2 | | |

SOT78 (TO-220AB)

Ordering information 3.

| Table 3. Ordering information | | | | | | |
|---------------------------------------|----------|--|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BTA312-800C | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | | |

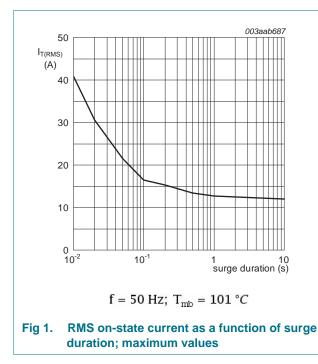
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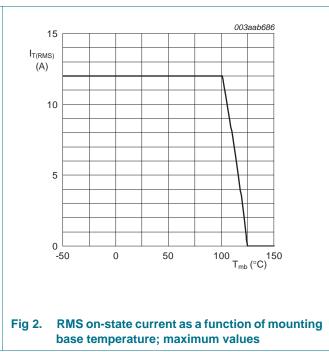
4. Limiting values

Table 4. Limiting values

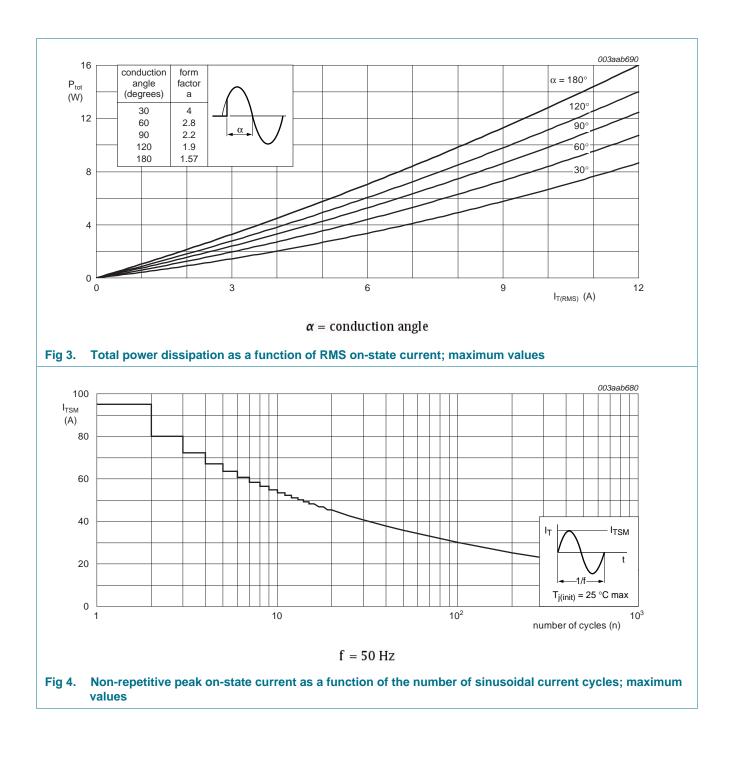
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|---|--|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 101 °C; see <u>Figure 3</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u> | - | 12 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; see <u>Figure 4</u> ; see <u>Figure 5</u> | - | 95 | А |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 16.7 ms | - | 105 | А |
| l ² t | I ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 45 | A ² s |
| dl _T /dt | rate of rise of on-state current | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

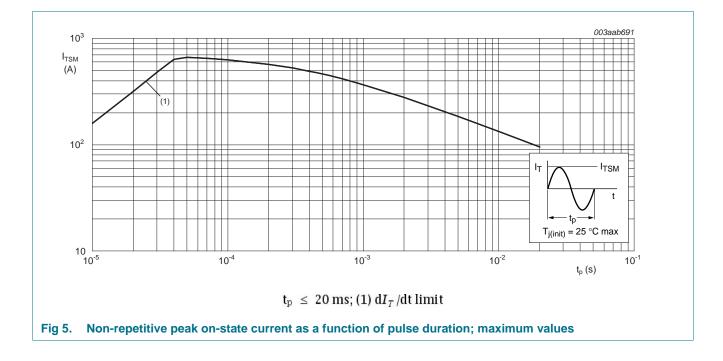




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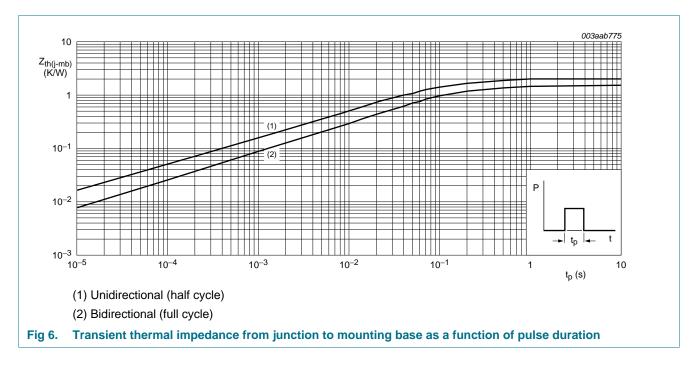
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5. Thermal characteristics

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| Table 5. | Thermal characteristics | | | | | |
|----------------------|---|--------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
| ui(j-110) | thermal resistance | full cycle; see Figure 6 | - | - | 1.5 | K/W |
| | from junction to mounting base | half cycle; see Figure 6 | - | - | 2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



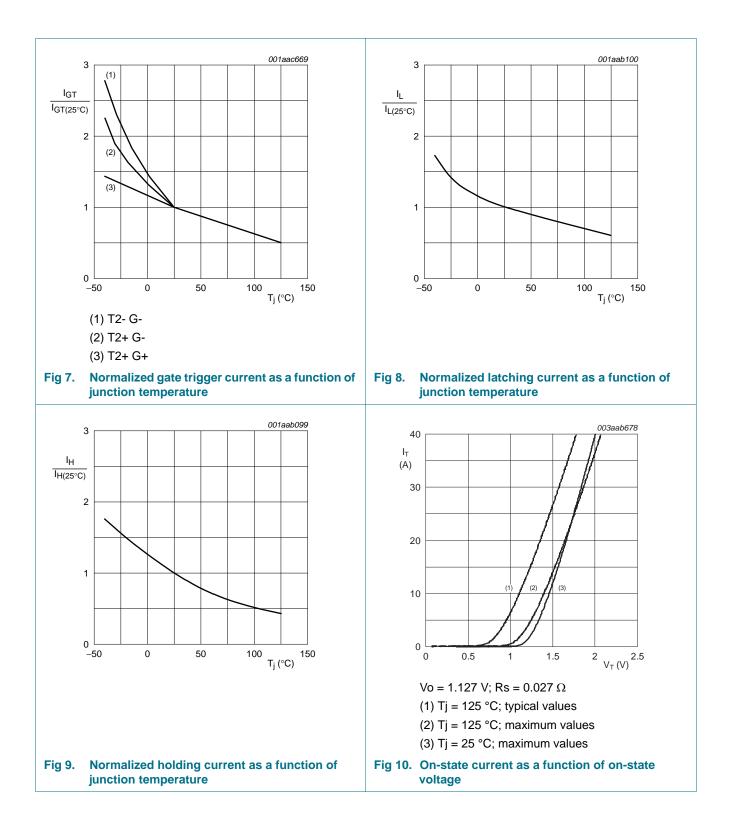
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6. Characteristics

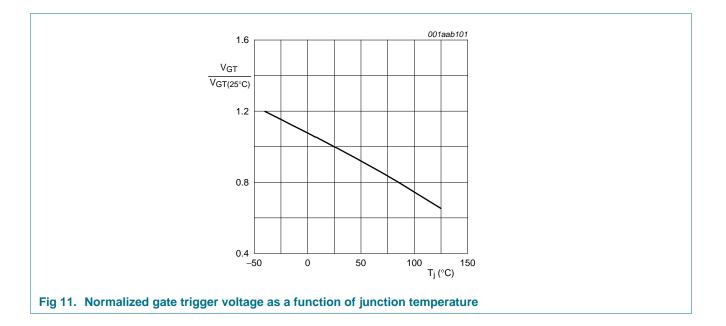
| Table 6. | Characteristics | | | | | |
|-----------------------|---------------------------------------|--|------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static cha | aracteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; see <u>Figure 7</u> | 2 | - | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; see <u>Figure 7</u> | 2 | - | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; see <u>Figure 7</u> | 2 | - | 35 | mA |
| ΙL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; see <u>Figure 8</u> | - | - | 50 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; see <u>Figure 8</u> | - | - | 60 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; see <u>Figure 8</u> | - | - | 50 | mA |
| I _H | holding current | $V_D = 12 \text{ V}; \text{ T}_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 9}}{100000000000000000000000000000000000$ | - | - | 35 | mA |
| VT | on-state voltage | I _T = 15 A; T _j = 25 °C; see <u>Figure 10</u> | - | 1.3 | 1.6 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; see <u>Figure 11</u> | - | 0.8 | 1.5 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; see <u>Figure 11</u> | 0.25 | 0.4 | - | V |
| I _D | off-state current | $V_{D} = 800 \text{ V}; \text{ T}_{j} = 125 \text{ °C}$ | - | 0.1 | 0.5 | mA |
| Dynamic | characteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T_j = 125 °C; exponential waveform; gate open circuit | 500 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | $V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s};$ gate open circuit; "without snubber" condition | 20 | - | - | A/ms |
| t _{gt} | gate-controlled turn-on time | $I_{TM} = 20 \text{ A}; \text{V}_{\text{D}} = 800 \text{V}; \text{I}_{\text{G}} = 0.1 \text{A}; \\ \text{d} \text{I}_{\text{G}}/\text{d} \text{t} = 5 \text{A}/\mu\text{s}$ | - | 2 | - | μs |
| | | | | | | |

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Package outline 7.

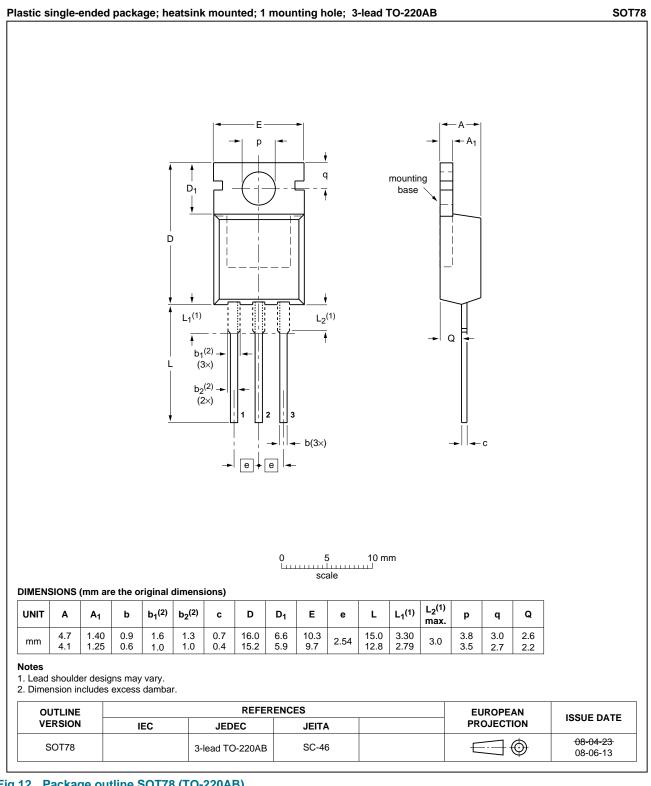


Fig 12. Package outline SOT78 (TO-220AB)

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8. Revision history

| Table 7. Revision hi | story | | | |
|----------------------|--|------------------------|-----------------------|--------------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| BTA312-800C v.2 | 20101129 | Product data sheet | - | BTA312_SER_B_C v.1 |
| Modifications: | Type number BTA3 | 12-800C separated from | data sheet BTA312_SEF | R_B_C v.1. |
| | Various changes to | content. | | |
| BTA312_SER_B_C v.1 | 20070313 | Product data sheet | - | - |

9. Legal information

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| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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